

COMPLEMENTARY SILICON POWER TRANSISTORS

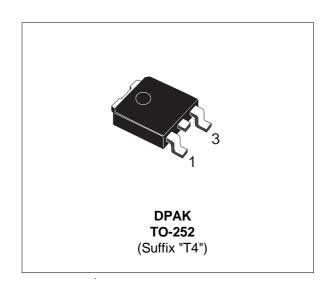
- STMicroelectronics PREFERRED SALESTYPES
- SURFACE-MOUNTING TO-252 (DPAK) POWER PACKAGE IN TAPE & REEL (SUFFIX "T4")
- ELECTRICALLY SIMILAR TO TIP31B/C AND TIP32B/C

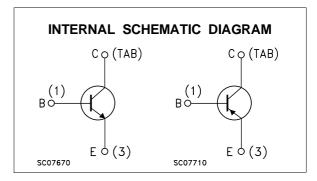
APPLICATIONS

 GENERAL PURPOSE SWITCHING AND AMPLIFIER TRANSISTORS

DESCRIPTION

The MJD31B and MJD31C and the MJD32B and MJD32C form complementary NPN-PNP pairs. They are manufactured using Epitaxial Base technology for cost-effective performance.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Va	Unit		
		NPN	MJD31B	MJD31C	
		PNP	MJD32B	MJD32C	
V _{CBO}	Collector-Base Voltage (I _E = 0)		80	100	V
V_{CEO}	Collector-Emitter Voltage (I _B = 0)		80	100	V
V_{EBO}	Emitter-Base Voltage (I _C = 0)			5	V
Ic	Collector Current		;	3	Α
I _{CM}	Collector Peak Current		;	5	Α
Ι _Β	Base Current			1	Α
P _{tot}	Total Dissipation at T _c = 25 °C		1	5	W
T _{stg}	Storage Temperature		-65 t	o 150	°C
Tj	Max. Operating Junction Temperature	1:	°C		

For PNP types the values are intented negative.

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MJD31B/31C - MJD32B/32C

THERMAL DATA

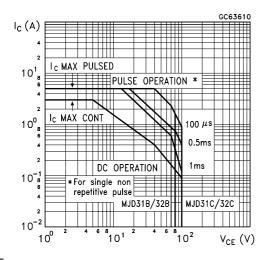
R _{thj-case}	Thermal Resistance Junction-case	Max	8.33	°C/W	
$R_{thj-amb}$	Thermal Resistance Junction-ambient	Max	100	°C/W	

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

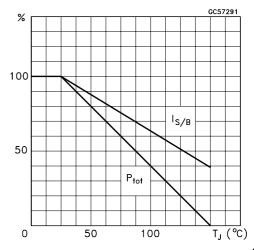
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut-off Current (V _{BE} = 0)	V _{CE} = Max Rating			20	μΑ
I _{CEO}	Collector Cut-off Current (I _B = 0)	V _{CE} = 60 V			50	μΑ
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 5 V			0.1	mA
V _{CEO(sus)}	Collector-Emitter Sustaining Voltage	I _C = 30 mA for MJD31B/32B for MJD31C/32C	80 100			V V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	$I_C = 3 \text{ A}$ $I_B = 375 \text{ mA}$			1.2	V
$V_{BE(on)}*$	Base-Emitter Voltage	I _C = 3 A V _{CE} = 4 V			1.8	V
h _{FE} *	DC Current Gain	I _C = 1 A	25 10		50	
h _{fe}	Dynamic Current Gain	I _C = 0.5 A V _{CE} = 10 V f = 1 KHz I _C = 0.5 A V _{CE} = 10 V f = 1 MHz	20 3			

^{*} Pulsed: Pulse duration = 300 μ s, duty cycle \leq 2 %

Safe Operating Area



Derating Curves

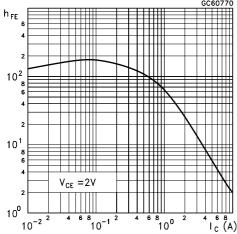


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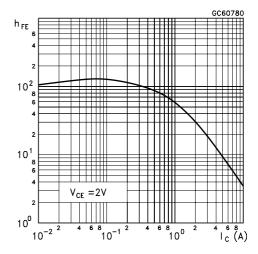
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For PNP type voltage and current values are negative.

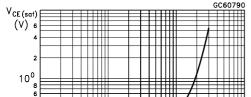
DC Current Gain (NPN type)



DC Current Gain (PNP type)

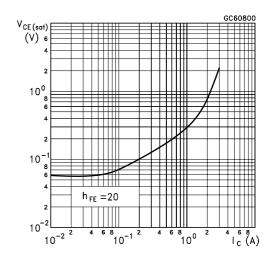


Collector-Emitter Saturation Voltage (NPN type)



GC60790

Collector-Emitter Saturation Voltage (PNP type)

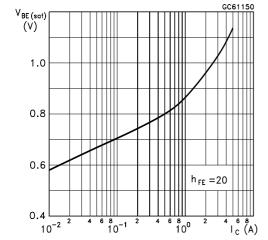


Base-Emitter Saturation Voltage (NPN type)

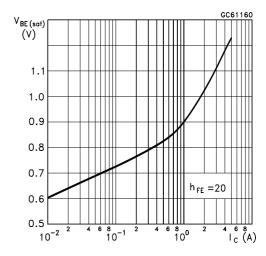
810⁰

4 6 8 10⁻¹ 2

 $h_{FE} = 20$



Collector-Base Capacitance (PNP type)

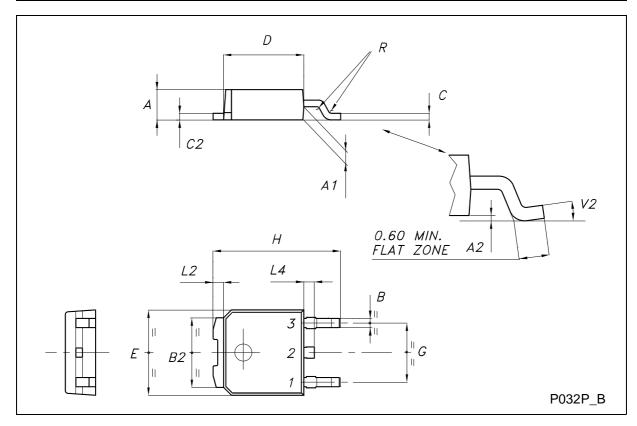


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TO-252 (DPAK) MECHANICAL DATA

DIM.	mm			inch			
DiW.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α	2.20		2.40	0.087		0.094	
A1	0.90		1.10	0.035		0.043	
A2	0.03		0.23	0.001		0.009	
В	0.64		0.90	0.025		0.035	
B2	5.20		5.40	0.204		0.213	
С	0.45		0.60	0.018		0.024	
C2	0.48		0.60	0.019		0.024	
D	6.00		6.20	0.236		0.244	
Е	6.40		6.60	0.252		0.260	
G	4.40		4.60	0.173		0.181	
Н	9.35		10.10	0.368		0.398	
L2		0.8			0.031		
L4	0.60		1.00	0.024		0.039	
V2	0°		8°	0°		0°	



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